



PHOTO DIODE NR8800FS-CB

ϕ 80 μ m InGaAs AVALANCHE PHOTO DIODE MODULE FOR OTDR APPLICATIONS

DESCRIPTION

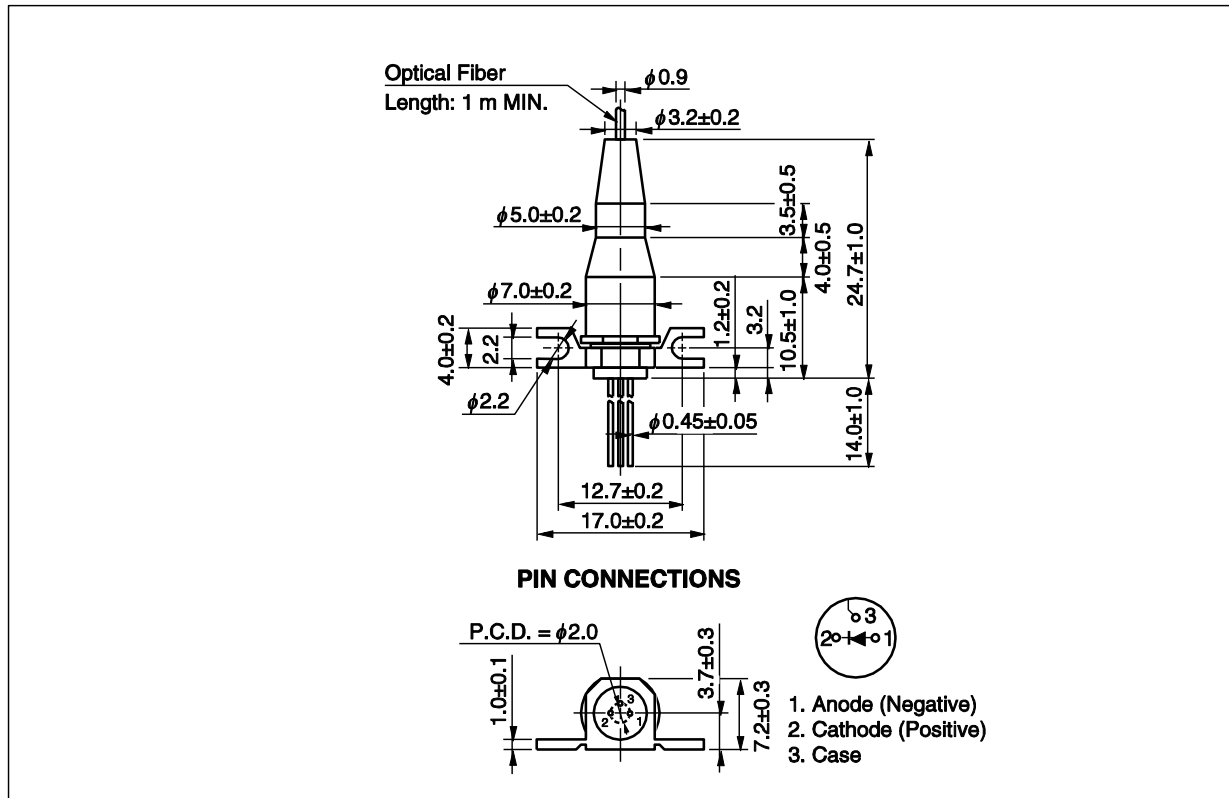
The NR8800FS-CB is an InGaAs avalanche photo diode module with multi mode fiber, and can be used in OTDR systems.

FEATURES

- Small dark current $I_D = 7$ nA
- Small terminal capacitance $C_t = 0.5$ pF @ $0.9 V_{(BR)R}$
- High sensitivity $S = 0.94$ A/W @ $\lambda = 1310$ nm, $M = 1$
- Detecting area size $\phi 80 \mu$ m
- Coaxial module with multi mode fiber (GI-62.5)

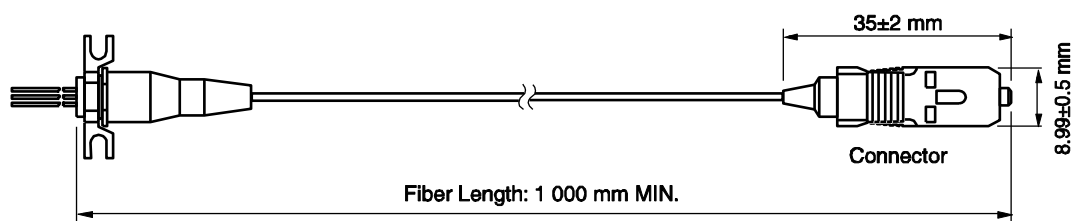
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<R> PACKAGE DIMENSIONS (UNIT: mm)



OPTICAL FIBER CHARACTERISTICS

Parameter	Specification	Unit
	GI-62.5 Fiber	
Core Diameter	62.5 ± 3	μm
Cladding Diameter	125 ± 2	μm
Maximum Cladding Noncircularity	2	%
Maximum Core/Cladding Concentricity	4.0	%
Outer Diameter	0.9 ± 0.1	mm
Minimum Fiber Bending Radius	30	mm
Fiber Length	1 000 MIN.	mm
Flammability	UL1581 VW-1	



<R> ORDERING INFORMATION

Part Number	Flange Type	Fiber Type	Available Connector
NR8800FS-CB-AZ	Flat Mount Flange	GI-62.5 Fiber	With SC-SPC Connector

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Forward Current	I_F	10	mA
Reverse Current	I_R	1.0	mA
Operating Case Temperature	T_C	–40 to +85	°C
Storage Temperature	T_{stg}	–40 to +85	°C
Lead Soldering Temperature	T_{sld}	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

ELECTRO-OPTICAL CHARACTERISTICS (T_c = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Reverse Breakdown Voltage	V _{BR}	I _D = 100 μA	50	70	100	V
Temperature Coefficient of Reverse Breakdown Voltage	δ ^{*1}			0.2		%/°C
Dark Current	I _D	V _R = V _{BR} × 0.9		7	30	nA
Multiplied Dark Current	I _{DM}	M = 2 to 10		1	5	nA
Terminal Capacitance	C _t	V _R = V _{BR} × 0.9, f = 1 MHz		0.5	0.75	pF
Sensitivity	S	λ = 1 310 nm, M = 1	0.8	0.94		A/W
Multiplication Factor	M	λ = 1 310 nm, I _{po} = 1.0 μA, V _R = V (@ I _D = 1 μA)	30	70		
Excess Noise Factor ^{*2}	x	λ = 1 310 nm, I _{po} = 1.0 μA,		0.7		
	F	M = 10, f = 35 MHz, B = 1 MHz		5		
Optical Return Loss	ORL	GI-62.5, λ = 1 310 nm	28			dB

$$*1 \delta = \frac{V_{BR}(25^{\circ}\text{C} + \Delta T^{\circ}\text{C}) - V_{BR}(25^{\circ}\text{C})}{\Delta T^{\circ}\text{C} \cdot V_{BR}(25^{\circ}\text{C})}$$

$$*2 F = M^x$$

REFERENCE

Document Name	Document No.
Opto-Electronics Devices Pamphlet	PX10160E

SAFETY INFORMATION ON THIS PRODUCT

Caution	GaAs Products	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.
Caution	Optical Fiber	<p>A glass-fiber is attached on the product. Handle with care.</p> <ul style="list-style-type: none"> • When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.